

Supporting Information

Excellent Nonlinear Optical Effects in MoS₂/CrOCl

Heterojunction

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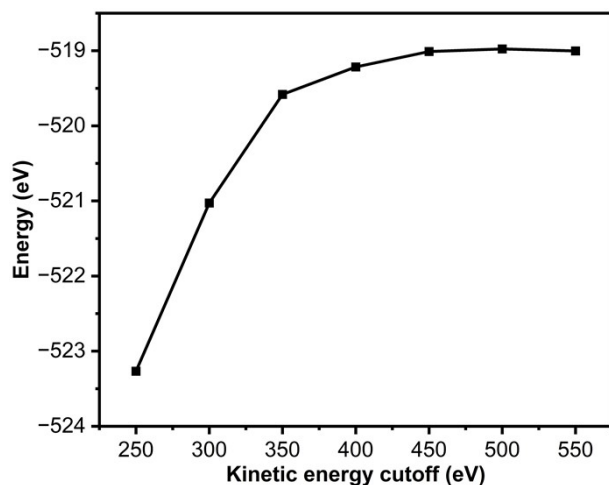


Figure S1. The total energy of the MoS₂/CrOCl heterojunction as a function of the kinetic energy cutoff for the planewave basis.

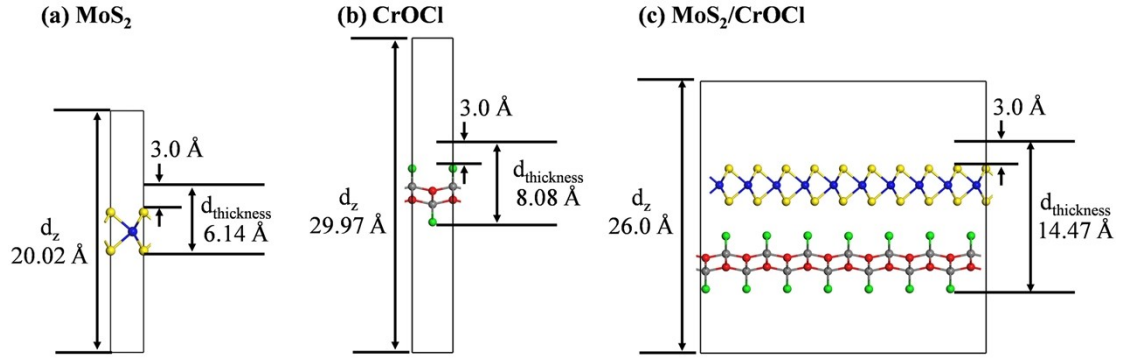


Figure S2. Details for the d_z and $d_{\text{thickness}}$ used in this study.

Table S1. Details about the lattice parameters of CrOCl supercell, MoS₂ supercell and MoS₂/CrOCl heterostructure. The strain in the CrOCl layer and MoS₂ layer along a and b directions are also listed. Here, a and b are lattice constants along x and y directions. A positive value means a tensile strain and a negative value means a compressive strain.

	CrOCl (7 × 1) supercell	MoS ₂ (5 × 1) supercell	MoS ₂ /CrOCl heterostructure	strain in CrOCl	strain in MoS ₂
a	27.288	27.407	27.347	0.22%	-0.22%
b	3.205	3.165	3.185	-0.62%	0.63%

The lattice constants of the MoS₂/CrOCl heterostructure were calculated as,

$$a_{\text{heter}} = (a_{\text{CrOCl}} + a_{\text{MoS}_2})/2,$$

$$b_{\text{heter}} = (b_{\text{CrOCl}} + b_{\text{MoS}_2})/2,$$

where, a_{heter} and b_{heter} are lattice constants of the MoS₂/CrOCl heterostructure. a_{CrOCl} , b_{CrOCl} , a_{MoS_2} and b_{MoS_2} are lattice constants of the CrOCl (7 × 1) supercell and MoS₂ (5 × 1) supercell.

The scanning of the potential energy surface of MoS₂/CrOCl heterostructures was performed by shifting the CrOCl layer along the x and y direction gradually (see Figure 1 in the main text). The grids are 56 × 7, i.e. a step of 0.488 Å along the x direction and a step of 0.455 Å along the y direction. For each configuration, all the atoms were fully relaxed including the interlayer distance.

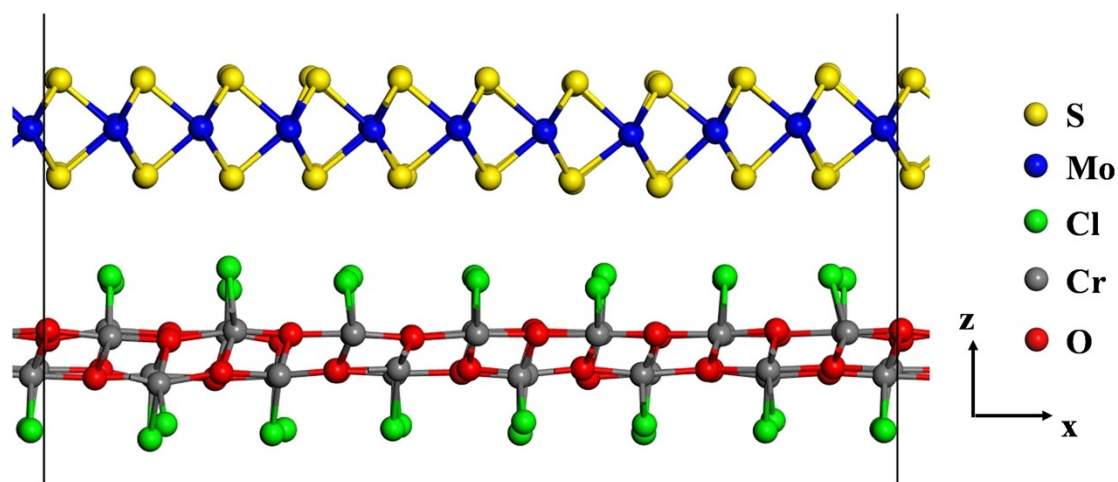


Figure S3. Snapshot structure of MoS₂/CrOCl heterostructure after 8 ps of AIMD simulations at 500K. The black rhombus represents the supercell used for AIMD.

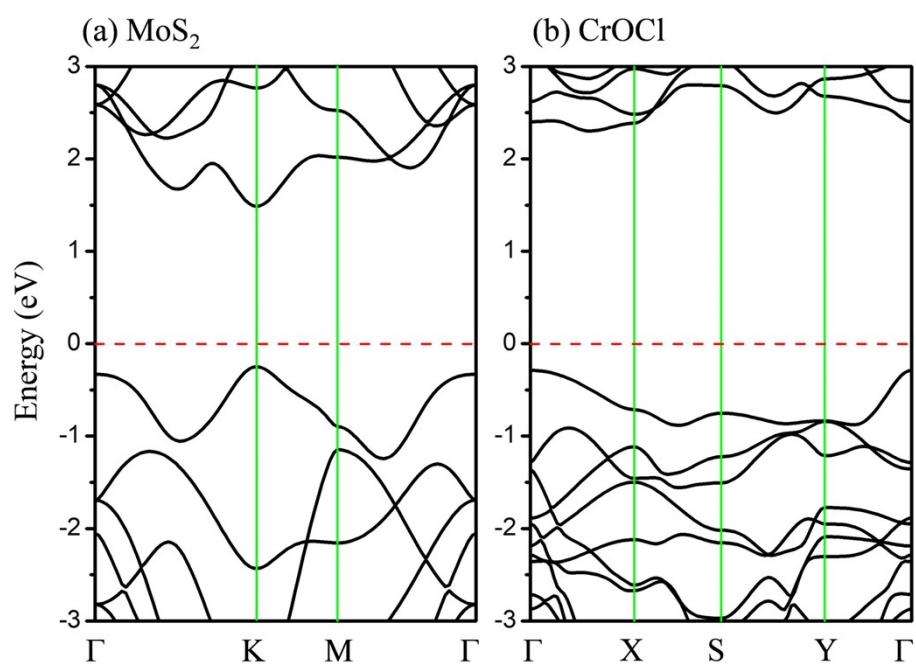


Figure S4. Band structure of (a) MoS₂ monolayer and (b) CrOCl monolayer.

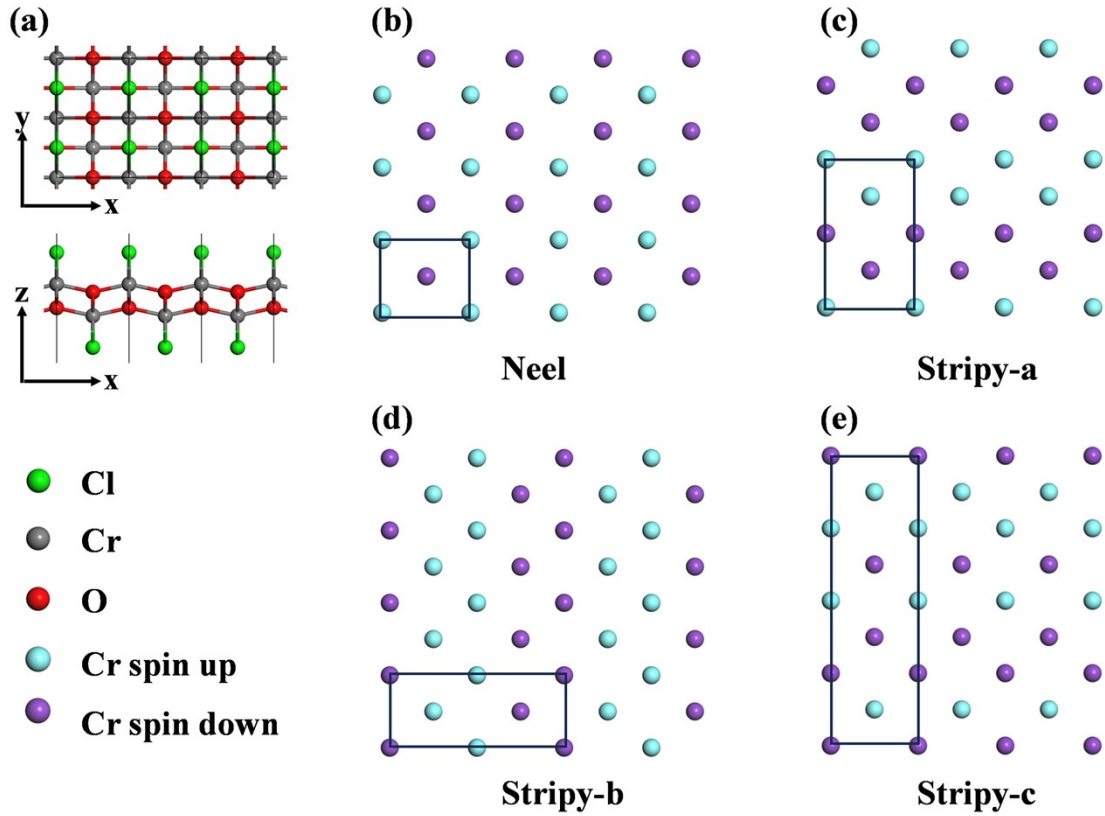


Figure S5. (a) Top and side views of monolayer CrOCl. (b-e) Top views of monolayer CrOCl with different antiferromagnetic configurations. Only Cr atoms are shown.

Table S2. Energy per CrOCl formula in monolayer CrOCl with non-magnetic (NM), ferromagnetic (FM) and antiferromagnetic (AFM-Neel, AFM-Stripy-a, AFM-Stripy-b, AFM-Stripy-c) states.

	NM	FM	AFM-Neel	AFM-Stripy-a	AFM-Stripy-b	AFM-Stripy-c
Energy (eV)	-18.522	-21.039	-21.068	-21.067	-21.065	-21.049

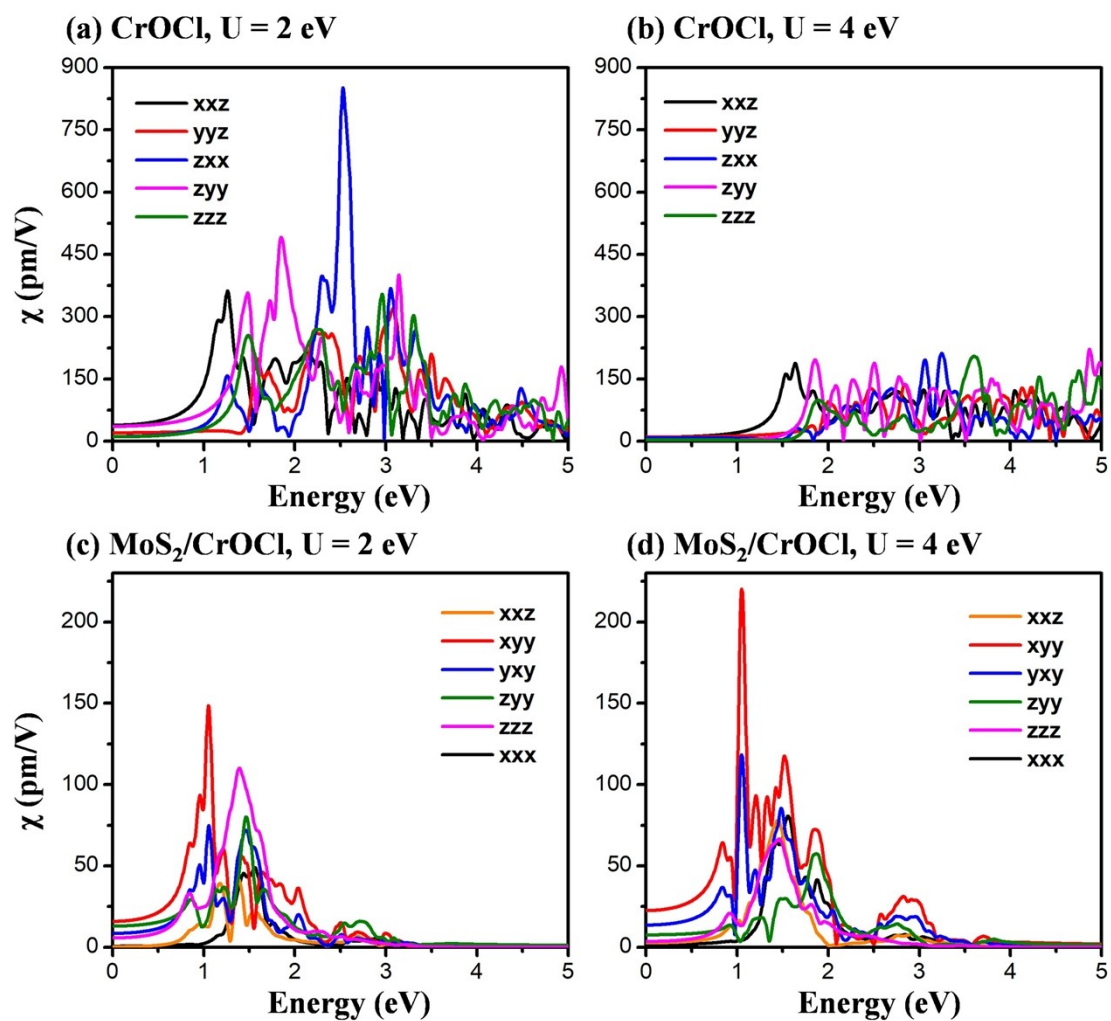


Figure S6. Non-zero second-order non-linear coefficients of (a-b) CrOCl and (c-d) MoS₂/CrOCl as functions of photon energy with different U values.

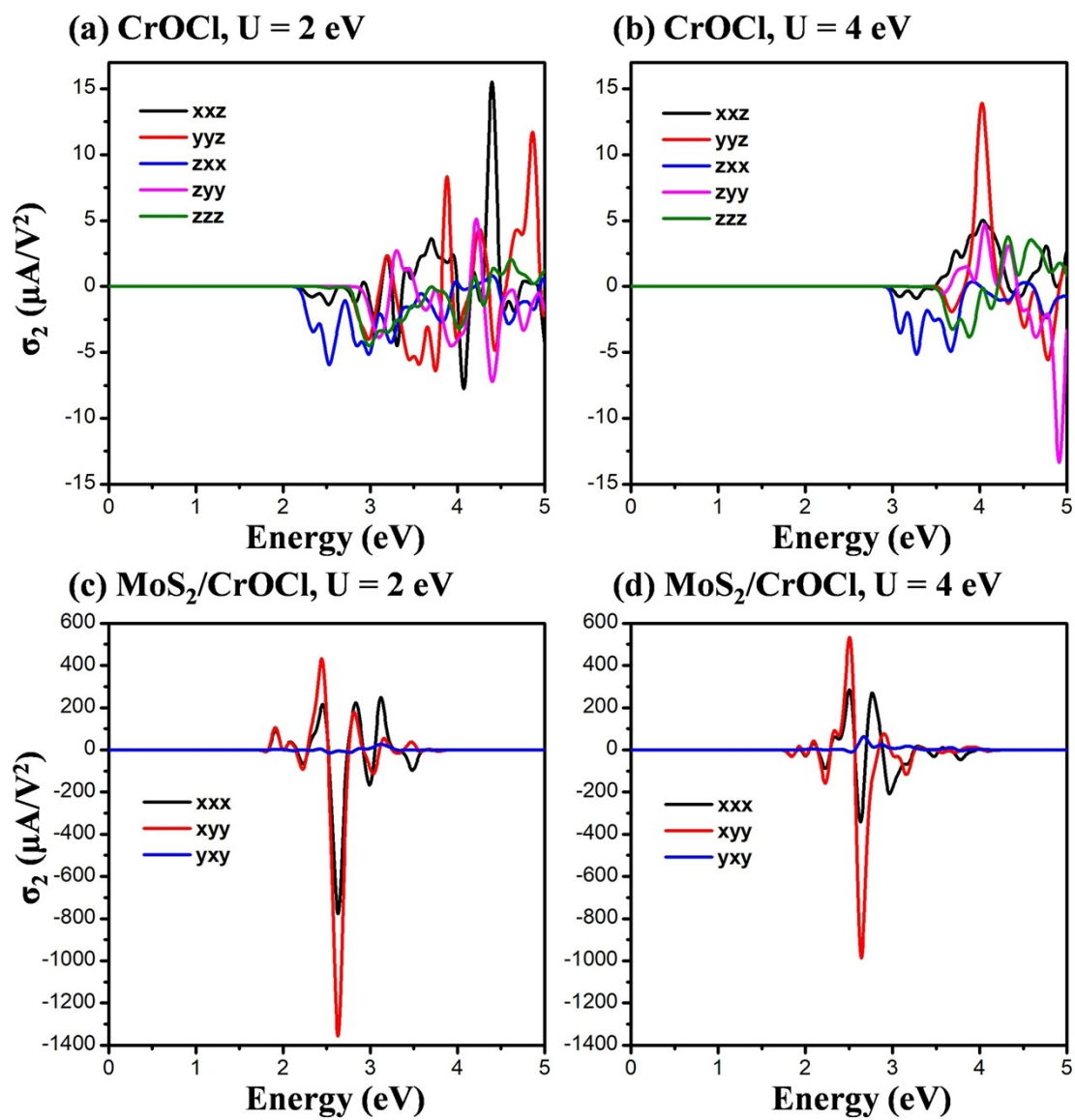


Figure S7. Shift photoconductivity versus photon energy of (a-b) CrOCl and (c-d) MoS₂/CrOCl with different U values.